

# FDS9431A F085

### P-Channel 2.5V Specified MOSFET

### **General Description**

This P-Channel 2.5V specified MOSFET is produced using Fairchild's proprietary, high cell density, DMOS technology. This very high density process has been especially tailored to minimize on-state resistance and yet maintain superior switching performance.

### **Applications**

- DC/DC converter
- Power management
- Load switch

Symbol

VDSS

 $V_{GSS}$ 

 $I_D$ 

 $P_{D}$ 

TJ, Tstq

· Battery protection

### February 2010

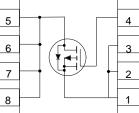
FDS9431A\_F085 P-Channel 2.5V Specified MOSFET

#### **Features**

-3.5 A, -20 V.  $R_{DS(ON)} = 0.130 \ \Omega @ V_{GS} = -4.5 \ V$  $\mathsf{R}_{_{\text{DS(ON)}}}$  = 0.180  $\Omega$  @  $\mathsf{V}_{_{\text{GS}}}$  = -2.5 V.

- · Fast switching speed.
- High density cell design for extremely low R<sub>DS(ON)</sub>.
- · High power and current handling capability.
- Qualified to AEC Q101
- RoHS Compliant

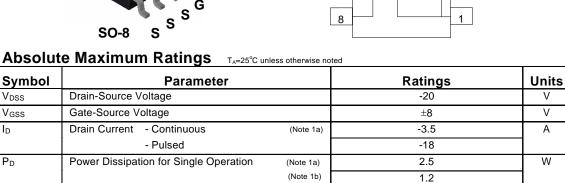




1.0

-55 to +150





(Note 1c)

## **Thermal Characteristics**

$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	(Note 1a)	50	°C/W
R <sub>θJC</sub>	Thermal Resistance, Junction-to-Case	(Note 1)	25	°C/W

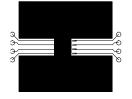
### **Package Marking and Ordering Information**

Operating and Storage Junction Temperature Range

Device Marking	Device	Reel Size	Tape width	Quantity
FDS9431A	FDS9431A_F085	13"	12mm	2500 units

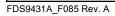
°C

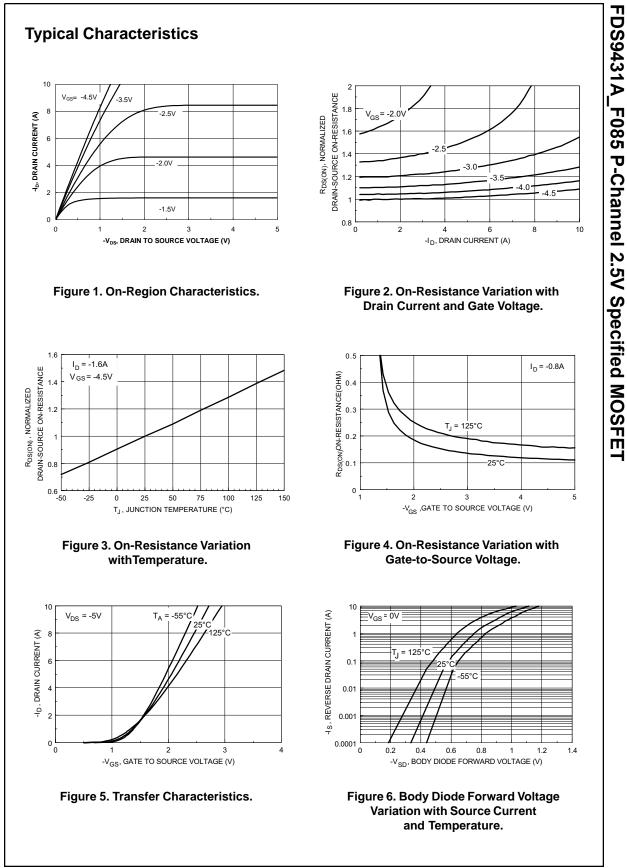
	Parameter	Test Conditions	Min	Тур	Мах	Units
Off Char	acteristics					
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> = 0 V, I <sub>D</sub> = -250 μA	-20			V
<u>ΔBVdss</u> ΔTj	Breakdown Voltage Temperature Coefficient	$I_D$ = -250 µA,Referenced to 25°C		-28		mV/°C
IDSS	Zero Gate Voltage Drain Current	$V_{DS} = -16$ V, $V_{GS} = 0$ V			-1	μA
I <sub>GSSF</sub>	Gate-Body Leakage Current, Forward	$V_{GS} = 8 V, V_{DS} = 0 V$			100	nA
I <sub>GSSR</sub>	Gate-Body Leakage Current, Reverse	$V_{GS} = -8 V, V_{DS} = 0 V$			-100	nA
On Char	acteristics (Note 2)					
V <sub>GS(th)</sub>	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_D = -250 \ \mu A$	-0.4	-0.6	-1	V
<u>ΔVgs(th)</u> ΔTJ	Gate Threshold Voltage Temperature Coefficient	$I_D$ = -250 µA,Referenced to 25°C		2		mV/°C
R <sub>DS(on)</sub>	Static Drain-Source	$V_{GS} = -4.5 V, I_D = -3.5 A$		0.110	0.130	Ω
	On-Resistance	V <sub>GS</sub> = -2.5 V, I <sub>D</sub> = -3.0 A V <sub>GS</sub> = -4.5 V, I <sub>D</sub> = -3.5 A		0.140 0.155	0.180 0.220	Ω
		T <sub>J</sub> =125°C		0.100	0.220	Ω
I <sub>D(on)</sub>	On-State Drain Current	$V_{GS} = -4.5 \text{ V}, \text{ V}_{DS} = -5 \text{ V}$	-10			A
<b>g</b> fs	Forward Transconductance	$V_{DS} = -5 V, I_D = -3.5 A$		6.5		S
Dynamic	Characteristics					
Ciss	Input Capacitance	$V_{DS} = -10 \text{ V}, \text{ V}_{GS} = 0 \text{ V},$		405		pF
Coss	Output Capacitance	f = 1.0 MHz		170		pF
C <sub>rss</sub>	Reverse Transfer Capacitance			45		pF
	g Characteristics (Note 2)	· · · · · ·				
t <sub>d(on)</sub>	Turn-On Delay Time	$V_{DD} = -5 V, I_D = -1 A,$ $V_{GS} = -4.5 V, R_{GEN} = 6 \Omega$		6.5	13	ns
t <sub>r</sub>	Turn-On Rise Time	VGS = 4.0 V, RGEN = 0.12		20	35	ns
t <sub>d(off)</sub>	Turn-Off Delay Time	_		31	50	ns
t <sub>f</sub>	Turn-Off Fall Time			21	35	ns
Q <sub>g</sub>	Total Gate Charge	$V_{DS} = -5 V, I_D = -3.5 A,$ $V_{GS} = -4.5 V$		6	8.5	nC
Q <sub>gs</sub>	Gate-Source Charge	VG3 - 1.0 V		0.8		nC
	Gate-Drain Charge			1.3		nC
-						
Q <sub>gd</sub> Drain-So	Durce Diode Characteristics a Maximum Continuous Drain-Source	0			-2.1	А



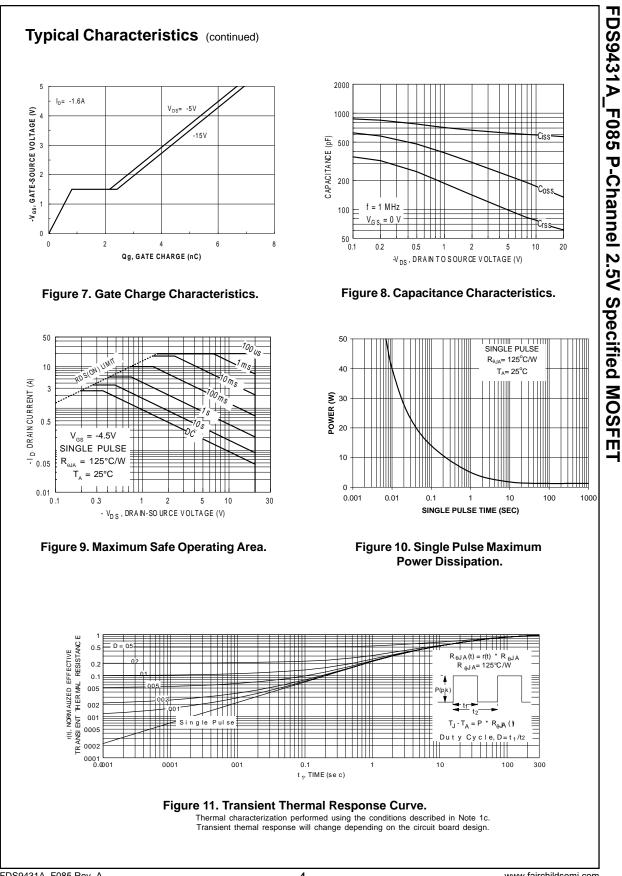
Scale 1 : 1 on letter size paper

2: Pulse Test: Pulse Width  $\leq$  300  $\mu s,$  Duty Cycle  $\leq$  2.0%





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